Design and Implementation of Series Resonant DC-DC Converter

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Abstract— The resonant DC-DC converter is known as advantageous over conventional DC-DC converter in terms of efficiency. This is primarily because the resonant converter operates at soft switching mode. In this paper, we report our work on the design and implementation of a series resonant DC-DC converter with full-bridge switching. The developed converter consisted of two main parts, namely the PWM signal-generating circuit as the driver for MOSFET and converter primary circuit. The first part was implemented by using Arduino UNO R3, whose output was amplified with IR2110 optocoupler. The latter was made up of full-bridge inverter, which employs MOSFET as the electronic switches, resonance circuit, and full-bridge uncontrolled rectifier. Performance of the developed converter functioned as a step-down "DC" transformer, i.e. voltage reducer. The maximum output voltage level obtained was half of the input, which was achieved at switching frequency of 40 kHz and efficiency of 50%. The converter was also tested to supply practical electrical load. In this case, a 12-V electric drill was put in place. The drill worked well, and a converter efficiency of 43% could be calculated during this operation.

Keywords : DC-DC Converter, Series Resonance and Switching

1. Introduction

In power electronic converters, higher switching frequency is preferable because it can decrease the converter size [1]. However, there will be a problem when the switching is not perfect. Imperfect switching is responsible for switching losses inside the converter circuits. Higher losses result in low converter efficiency.

One way to reduce this switching losses is by employing resonant circuit, in which the switching scheme is referred to as "soft switching" [2]. In soft switching, on-off transitions occur when the values of voltage and current are zero. Soft switching was introduced to obtain high-efficiency converter and to reduce electromagnet interference (EMI) level as well [3].

Among the converters that can apply the principle of soft switching is the DC-DC converter. DC-DC converters have found many applications in power system, mainly for the purpose of interfacing renewable energy (e.g. wind turbine, solar cell) to existing power system [4], [5]. Special form of DC-DC converters that employ soft switching is called resonant DC-DC converters. In resonant DC-DC converters, output voltage is controlled by varying

circuit's switching frequency [6].

Being attracted to these advantages, we have developed small-scale series resonant DC-DC converter and we aim to present the result in this paper. We start by describing basic concept of resonant DC-DC converter, especially series resonant converter. Subsequently, we explain the design and implementation work involved. Afterwards, we elaborate converter's performance in details.

2. Concept of Series Resonance DC-DC Converter

Series resonant DC-DC converter is DC-DC converter whose output voltage is governed by its switching frequency. The term "series" represent its series connection between capacitor and inductor in its resonant circuit [7]. Signal flow in series resonant DC-DC converter is processed in three stages. In first stage, input DC voltage is converted to AC by means of full-bridge inverter. The second stage involves tuning the switching frequency in order to obtain resonance. In the last stage, the AC signal is converter back to DC

Received date 2019-12-15, Revised date 2020-03-09, Accepted date 2020-03-09 https://doi.org/10.25077/jnte.v9n1.736.2020 This work is licensed under a <u>Creative Commons Attribution-ShareAlike 4.0 International License</u>. through full-bridge rectifier. Configuration of series resonant DC-DC converter is shown in Fig. 1.

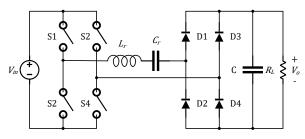


Figure 1. Circuit diagram of series resonant DC-DC converter

Resonant network consists of series connection of inductor L_r and capacitor C_r . The important parameters of the converter are defined in (1)-(4),

$$X_L = \omega_s L_r \tag{1}$$

$$X_C = \frac{1}{\omega_s C_r} \tag{2}$$

$$\omega_s = 2\pi f_s \tag{3}$$

$$f_r = \frac{1}{2\pi\sqrt{L_r C_r}} \tag{4}$$

where X_L is inductive reactance of L_r (Ω), X_C is capacitive reactance of C_r (Ω), f_r is circuit resonant frequency (Hz), and f_s and ω_s is circuit switching frequency (Hz) and angular switching frequency (rad/s), respectively.

The magnitude of output voltage V_o is regulated by controlling switching frequency ω_s . This is governed by (5),

$$\frac{V_o}{V_{in}} = \frac{1}{2} \left(\frac{1}{\sqrt{1 + \left[(X_L - X_C) / R_{eq} \right]^2}} \right)$$
(5)

where V_{in} is circuit input voltage (V) and R_{eq} is circuit equivalent resistance. The term V_o/V_{in} is also known as voltage gain. R_{eq} is approximated by (6),

$$R_{eq} = \left(\frac{8}{\pi^2}\right) R_L \tag{6}$$

where R_L is the load resistance (Ω). The sensitivity of the output to the switching frequency depends of the values of L_r and C_r .

Another important parameter of series resonant DC-DC converter is the circuit quality factor Q, which is defined by (7),

$$Q = \frac{\omega_r L_r}{R_L} \tag{7}$$

where ω_r is the circuit resonant frequency (rad/s). How *Q* value affects the voltage gain is depicted in Fig. 2. As shown in Fig. 2, maximum output voltage is theoretically equal to input voltage when circuit operates at resonant frequency, $\omega_s = \omega_r$.

Ideally, converter output power is equal to its input power. However, voltage drop V_{cH} introduced during switching of four MOSFET in the inverter part obviously contributes to the power loss [8], which could reduce circuit efficiency. Converter efficiency η is calculated as in (8).

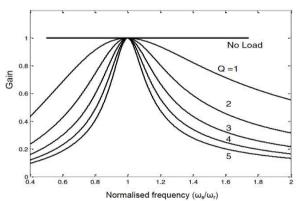


Figure 2. Normalized frequency response of series resonant DC-DC converter

$$\eta = \frac{P_o}{P_{in}} \times 100\% \tag{8}$$

where input and output powers are calculated as in (9) and (10),

$$P_{in} = \frac{1}{T} \int_{0}^{kT} v_0 I_0 dt$$

= $\frac{1}{T} \int_{0}^{kT} \frac{V_0^2}{R_L} dt = \frac{k V_{in}^2}{R_L}$ (9)

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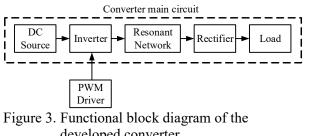
$$P_{o} = \frac{1}{T} \int_{0}^{kT} \frac{V_{0}^{2}}{R} dt$$

$$= \frac{1}{T} \int_{0}^{kT} \frac{(V_{in} - V_{cH})^{2}}{R_{L}} dt$$

$$= k \frac{(V_{in} - V_{cH})^{2}}{R_{L}}$$
(10)

3. Converter Design and Implementation

As indicated in previous section, the developed series resonant DC-DC converter was made up two parts, namely driver circuit and main circuit. In main circuit, input voltage was converted to AC and then converted back to DC. Fig. 3 shows the block diagram of the developed converter, while Table 1 lists its specification. In this converter, electronic switches used in inverter circuit are MOSFET.



developed converter

Table 1. Design parameter of the developed converter

	•1
Parameter	Value
Input Voltage	20 V _{DC} - 30 V _{DC}
Input Current	0,1 A – 0,73 A
Input Power	$2 \mathrm{W} - 22 \mathrm{W}$
MOSFET Gate Voltage	$12 V_{DC}$
Resonant Frequency	50 kHz
Switching Frequency	10 kHz – 100 kHz
Duty Cycle	50 %
Maximum Output Current	0,73 A
Maximum Output Voltage	15 V _{DC}
Maximum Output Power	11 W

Desired converter parameters, as in Table 1, are to be achieved through the following design steps.

a. Design of PWM controller circuit

PWM signals are used for controlling switching mechanism of the full-bridge inverter. In our converter, we utilize Arduino UNO R3 for this purpose. PWM signals were generated in the range of 10-100 kHz with duty cycle of 50%. These signals were of 5-V amplitude and in our practice, this value was not high enough to drive the inverter's MOSFET into saturation area. Therefore, we amplified these signals before injecting them into the MOSFET of full-bridge inverter. A value of 12 V was found to be enough to fire the MOSFET. IR2110 optocoupler was employed for this task.

b. Design of full-bridge inverter circuit

In our inverter circuit, we used IRFZ44N series MOSFET for switching. Its specification is presented below,

- Drain source breakdown voltage: 55 V
- Gate source breakdown voltage: 20 V
- Gate threshold voltage V_{Th} : 4 V
- Drain source ON resistance R_{DS(ON)}: 0.0175
 Ω

Fig. 4 shows the relationship between gate-tosource voltage V_{GS} and I_D of IRFZ44N. As shown in Fig. 4, theoretically a V_{GS} value of 5 V is enough to drive the MOSFET to ON mode. However, practically it is not in such way. We set V_{GS} to maximum allowable values of 12 V.

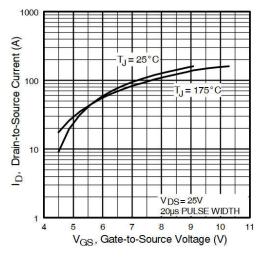


Figure 4. I_D vs V_{GS} relationship of IRFZ44N series MOSFET [9]

c. Design of resonant circuit

In resonant circuit, a 100-nF capacitor and a 100- μ H were used. Therefore, by using (4), resonant frequency of the circuit was found to be 50.35 kHz, or 316223.12 in terms of rad/s. Because maximum power that can be handled by the developed converter is around 20 W, we

choose ceramic resistor of 20 W/22RJ as converter load. According to (6), circuit equivalent resistor R_{eq} was found to be 17.85 Ω . Also, quality factor Q was also calculated using (7) and was found to be 1.771.

d. Design of full-bridge rectifier

As uncontrolled rectifier is enough [10], we used diode for the purpose of rectification. Ultrafast diode of UF4007 series was put in place. This type of diode has a voltage limit of 1000 V and a current limit of 1 A. To reduce the ripple of the rectifier output, a capacitor of 1000 μ F was employed as filter. This capacitor was placed in parallel with the load.

4. Results and Discussions

The developed series resonant DC-DC converter is shown in Fig. 5. The first conducted experiment was varying switching frequency at fixed input voltage. We took two input voltage values for comparison. The switching frequency was then plotted against output voltage V_o and output current I_o . The results are shown in Fig. 6 and Fig. 7.

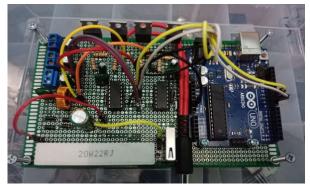


Figure 5. The implemented series resonant DC-DC converter

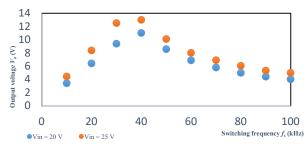


Figure 6. Output voltage vs switching frequency of the developed converter

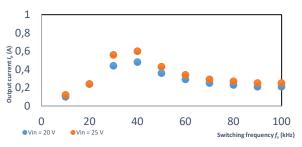
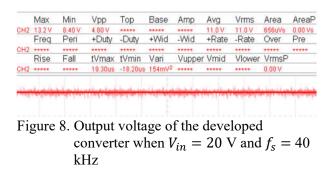


Figure 7. Output current vs switching frequency of the developed converter

As can be seen in Fig. 6 and Fig. 7, the maximum output voltage and current of the developed converter were achieved when switching frequency was at 40 kHz and the minimum output voltage and current were obtained at switching frequency of 10 kHz. Maximum recorded voltage values are 10.4 V and 13.1 V for input voltage values of 20 V and 25 V, respectively. The switching frequency of 40 kHz is actually close to the theoretical resonant frequency of around 50 kHz. However, this error could be accepted since the output voltage and current at switching frequency of 50 kHz is not that different from those at 40 kHz.

The second test was aimed at observing converter voltage efficiency. This test was conducted at optimal frequency, which is 40 kHz, as stated before. Similar to the previous one, it was carried out by measuring converter output voltage at different input voltage values. The results for $V_{in} = 20$ V, $V_{in} = 25$ V, and $V_{in} = 30$ V are presented in Fig. 8, Fig. 9, and Fig. 10, respectively. As converter is designated to produce half of input voltage, voltage efficiency was judged on how much output voltage differs from it. As can be seen in Fig. 8, Fig. 9, and Fig. 10, the output voltage values are more than 90% of the values they are supposed to be, i.e. 94.7% for $V_{in} = 20$ V, 91.6% for $V_{in} = 25$ V, and 92.2% for $V_{in} = 30$ V.



	Max	Min	Vpp	Тор	Base	Amp	Avg	Vrms	Area	AreaF
CH2	15.2.V	10.8 V	4.40 V				13.0 V	13.0 V	778uVs	0.00 Vs
	Freq	Peri	+Duty	-Duty	+Wid	-Wid	+Rate	-Rate	Over	Pre
CH2			*****	*****	*****				*****	
	Rise	Fall	tVmax	tVmin	Vari	Vupper	Vmid	Vlower	VrmsP	
CH2	*****	*****	-17.40us	-29.90us	179mV ²				0.00 V	

Figure 9. Output voltage of the developed converter when $V_{in} = 25$ V and $f_s = 40$ kHz

	Max	Min	Vpp	Тор	Base	Amp	Avg	Vrms	Area	AreaP
CH2	18.4 V	11.6 V	6.80 V	18.4 V	11.6 V	6.80 V	15.2 V	15.4 V	912mVs	13.6mVs
	Freq	Peri	+Duty	-Duty	+Wid	-Wid	+Rate	-Rate	Over	Pre
CH2	1.11kHz	900.0us	5.555 %	94.44 %	50.00us	850.0us	4.18kV/s			
	Rise	Fall	tVmax	tVmin	Vari	Vupper	Vmid	Vlower	VrmsP	
CH2	1.300ms		-1.125ms	374.8us	4.67 V2	17.7 V	15.0 V	12.3 V	15.3 V	

Figure 10. Output voltage of the developed converter when $V_{in} = 30$ V and $f_s = 40$ kHz

The third assessment involved observing converter power efficiency. This was done by calculating output power and efficiency using (8). The calculation results for different switching frequencies are presented in Table 2, Table 3, and Table 4. As can be seen, with input power of approximately 20 W, converter produced half of it, indicating a power efficiency of about 50%.

Switching frequency f_s	Output voltage V _o	Output current I _o	Output power P _o
10 kHz	3,42 V	0,1 A	0,342 W
20 kHz	6,41 V	0,24 A	1,54 W
30 kHz	9,40 V	0,44 A	4,14 W
40 kHz	10,40 V	0,48 A	5 W
50 kHz	8,56 V	0,36 A	3,08 W
60 kHz	6,88 V	0,29 A	2 W
70 kHz	5,79 V	0,25 A	1,45 W
80 kHz	4,98 V	0,23 A	1,15 W
90 kHz	4,40 V	0,21 A	0,92 W
100 kHz	4,02 V	0,21 A	0,844 W

Table 2. Converter output for $V_{in} = 20$ V

Table 3. Converter output for $V_{in} = 25$ V

SwitchingOutputfrequency f_s voltage	1 1
10 kHz 4,43 V	0,12 A 0,53 W
20 kHz 8,38 V	0,29 A 2,43 W
30 kHz 12,50 V	V 0,56 A 7 W
40 kHz 13,1 V	0,43 A 5,63 W
50 kHz 10,10 V	V 0,34 A 3,43 W
60 kHz 8,12 V	0,29 A 2,35 W
70 kHz 6,90 V	0,29 A 2 W
80 kHz 6,06 V	0,27 A 1,64 W

Switching frequency f_s	Output voltage V _o	Output current I _o	Output power P _o
90 kHz	5,34 V	0,25 A	1,34 W
100 kHz	4,98 V	0,25 A	1,25 W

Table 4. Converter output for $V_{in} = 30$ V

Switching frequency f_s	Output voltage V_o	Output current I_o	Output power P _o
10 kHz	8,43 V	0,32 A	2,70 W
20 kHz	10,27 V	0,59 A	6,06 W
30 kHz	13,30 V	0,66 A	8,78 W
40 kHz	15 V	0,73 A	11 W
50 kHz	13,13 V	0,61 A	8 W
60 kHz	12,24 V	0,49 A	6 W
70 kHz	11,35 V	0,44	5 W
80 kHz	10,87 V	0,37 A	4,02 W
90 kHz	9,56 V	0,30 A	2,87 W
100 kHz	9,32 V	0,30 A	2,8 W

In addition, the developed converter was also tested with practical load of a 12-V electric drill. This test was performed to see converter performance when its load was increased. The output voltage before and after being connected to the electric drill measured by oscilloscope are shown in Fig. 11 and Fig. 12.

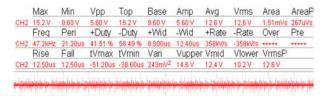


Figure 11. Output voltage of the developed converter before being connected to drill

	Max	Min	Vpp	Тор	Base	Amp	Avg	Vrms	Area	AreaF
CH2	12.8 V	8.00 V	4.80 V	*****			10.4 V	10.4 V	1.24mVs	0.00 Vs
	Freq	Peri	+Duty	-Duty	+Wid	-Wid	+Rate	-Rate	Over	Pre
H2				*****				*****	*****	*****
	Rise	Fall	tVmax	tVmin	Vari	Vupper	Vmid	Vlower	VrmsP	
HZ		*****	-57.00us	-44.40us	443mV ²				0.00 V	

Figure 12. Output voltage of the developed converter after being connected to drill

This electric drill connection experiment showed that there was a decrease in converter output voltage of about 2.2 V. In other words, voltage gain decreased from 0.525 to 0.433. This gain decrease is actually related to the change of converter quality factor Q due to insertion of electric drill. Q itself is affected by converter equivalent resistance R_{eq} , as in (7). With the introduction of electric drill, R_{eq} dropped and Q increases, which in turn affected output voltage.

5. Conclusion

A small series resonant DC-DC converter has been designed and implemented in this paper. Converter worked by two stages of power conversion, i.e. DC to AC conversion and AC to DC conversion. Output voltage was less than input voltage, resulting in converter work as voltage reducer. In terms of output voltage accuracy, achieved output voltage was very close theoretical value, i.e. around 90% accuracy. In terms of power efficiency, the developed converter achieved an efficiency of about 50%. When electric drill was connected, the drill worked well but has reduced converter efficiency to a value of about 43%.

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